## **FEATURES**

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- · High efficiency operation
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- T<sub>.1</sub> 200 °C max. in solar bypass mode application
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### TYPICAL APPLICATIONS

For use in solar cell junction box as a bypass diode for protection, using DC forward current without reverse bias.

## **MECHANICAL DATA**

Case: TO-220AB, TO-262AA Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

#### Polarity: As marked

Mounting Torque: 10 in-lbs maximum

<b>MAXIMUM RATINGS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)							
PARAMETER		SYMBOL	VT2045CBP	VIT2045CBP	UNIT		
Maximum repetitive peak reverse voltage		V <sub>RRM</sub>	45		V		
Maximum average forward rectified current (fig. 1)	per device	I	20		A		
	per diode	I <sub>F(AV)</sub> <sup>(1)</sup>	10				
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I <sub>FSM</sub>	160		А		
Operating junction and storage temperature range (AC mode)		T <sub>OP</sub> , T <sub>STG</sub>	-40 to +150		°C		
Junction temperature in DC forward current without reverse bias, $t \leq 1 \ h$		T <sub>J</sub> <sup>(2)</sup>	≤ 200		°C		

Notes

<sup>(1)</sup> With heatsink

<sup>(2)</sup> Meets the requirements of IEC 61215 ed. 2 bypass diode thermal test

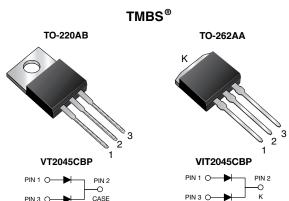
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1

**Trench MOS Barrier Schottky Rectifier** for PV Solar Cell Bypass Protection

Ultra Low  $V_F = 0.33$  V at  $I_F = 5.0$  A



2 x 10 A

45 V

160 A

0.41 V

150 °C

200 °C

TO-220AB, TO-262AA

Dual common cathode

**PRIMARY CHARACTERISTICS** 

I<sub>F(AV)</sub>

V<sub>RRM</sub>

I<sub>FSM</sub>

 $V_F$  at  $I_F = 10 A$ 

T<sub>OP</sub> max. (AC mode)

T<sub>J</sub> max. (DC forward current)

Package

**Diode variation** 

www.vishay.com

# **VT2045CBP, VIT2045CBP**

Vishay General Semiconductor



RoHS COMPLIANT

HALOGEN FREE



## Vishay General Semiconductor

ELECTRICAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I <sub>F</sub> = 5 A	T₄ = 25 °C	- V <sub>F</sub> <sup>(1)</sup>	0.44	-	V
	I <sub>F</sub> = 10 A			0.49	0.58	
	I <sub>F</sub> = 5 A	– T <sub>A</sub> = 125 °C		0.33	-	
	I <sub>F</sub> = 10 A			0.41	0.52	
Reverse current per diode	V <sub>B</sub> = 45 V	T <sub>A</sub> = 25 °C	1 (2)	-	2000	μA
	$V_{\rm R} = 45 V$ $T_{\rm A} = 12$	T <sub>A</sub> = 125 °C	I <sub>R</sub> <sup>(2)</sup>	10	30	mA

Notes

<sup>(1)</sup> Pulse test: 300 µs pulse width, 1 % duty cycle

 $^{(2)}\,$  Pulse test: Pulse width  $\leq 40\mbox{ ms}$ 

<b>THERMAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)							
PARAMETER		SYMBOL	VT2045CBP	VIT2045CBP	UNIT		
Typical thermal resistance	per diode	В	3.0		°C/W		
	per device	R <sub>θJC</sub>	2.0				

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-220AB	VT2045CBP-M3/4W	1.88	4W	50/tube	Tube	
TO-2262AA	VIT2045CBP-M3/4W	1.45	4W	50/tube	Tube	



## VT2045CBP, VIT2045CBP

Vishay General Semiconductor

## **RATINGS AND CHARACTERISTICS CURVES** ( $T_A = 25$ °C unless otherwise noted)

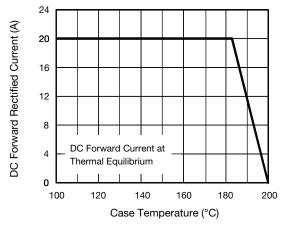


Fig. 1 - Maximum Forward Current Derating Curve

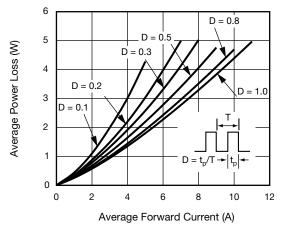


Fig. 2 - Forward Power Loss Characteristics Per Diode

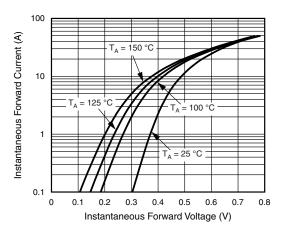


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

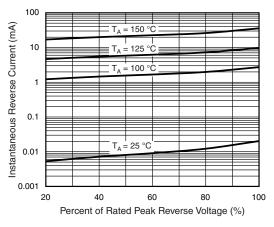


Fig. 4 - Typical Reverse Characteristics Per Diode

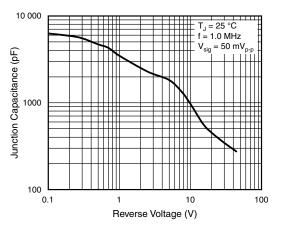


Fig. 5 - Typical Junction Capacitance Per Diode

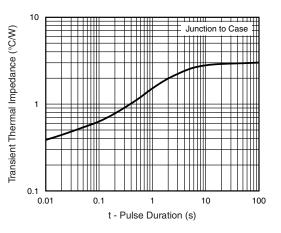


Fig. 6 - Typical Transient Thermal Impedance Per Diode

Revision: 15-Dec-16

3

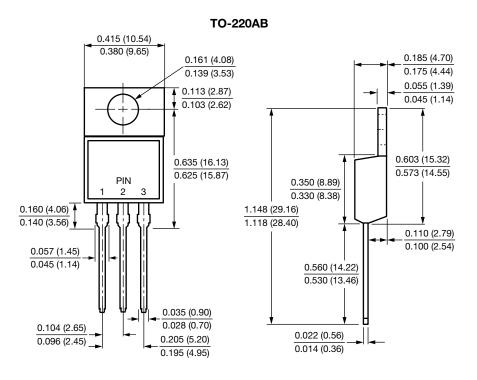
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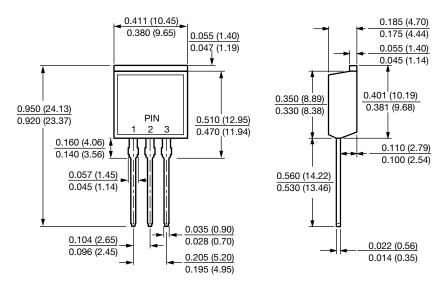
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#### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)



**TO-262AA** 





Vishay

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